

2MBI200SB-120

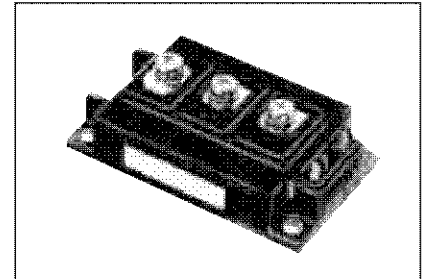
IGBT MODULE (S series) 1200V / 200A / 2 in one package

■ Features

- High speed switching
- Voltage drive
- Low Inductance module structure

■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply
- Industrial machines, such as Welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

| Items | Symbols | Conditions | Maximum ratings | Units | |
|-----------------------------|----------------------|------------|-----------------|-------|---|
| Collector-Emitter voltage | V _{CEs} | | 1200 | V | |
| Gate-Emitter voltage | V _{GEs} | | ±20 | V | |
| Collector current | I _c | Continuous | Tc=25°C | 300 | A |
| | | | Tc=80°C | 200 | |
| | I _c pulse | 1ms | Tc=25°C | 600 | |
| | | | Tc=80°C | 400 | |
| | -I _c | | | 200 | |
| -I _c pulse | 1ms | | 400 | | |
| Collector power dissipation | P _c | 1 device | 1500 | W | |
| Junction temperature | T _j | | 150 | °C | |
| Storage temperature | T _{stg} | | -40 to +125 | °C | |
| Isolation voltage (*1) | V _{iso} | AC : 1min. | 2500 | V | |
| Screw torque | Mounting (*2) | | 3.5 | N·m | |
| | Terminals (*2) | | 4.5 | | |

Note *1: All terminals should be connected together when isolation test will be done.

Note *2: Recommendable value : Mounting : 2.5-3.5 N·m (M5 or M6), Terminals : 3.5-4.5 N·m (M6)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

| Items | Symbols | Conditions | Characteristics | | | Units | |
|--------------------------------------|----------------------|---|-----------------------|-------|------|-------|---|
| | | | min. | typ. | max. | | |
| Zero gate voltage collector current | I _{CEs} | V _{GE} = 0V, V _{CE} = 1200V | - | - | 1.0 | mA | |
| Gate-Emitter leakage current | I _{GES} | V _{CE} = 0V, V _{GE} = ±20V | - | - | 0.4 | µA | |
| Gate-Emitter threshold voltage | V _{GE(th)} | V _{CE} = 20V, I _c = 200mA | 5.5 | 7.2 | 8.5 | V | |
| Collector-Emitter saturation voltage | V _{CE(sat)} | V _{GE} = 15V I _c = 200A | T _j =25°C | - | 2.3 | 2.6 | V |
| | | | T _j =125°C | - | 2.8 | - | |
| Input capacitance | C _{ies} | V _{GE} = 0V | - | 24000 | - | pF | |
| Output capacitance | C _{oes} | V _{CE} = 10V | - | 5000 | - | | |
| Reverse transfer capacitance | C _{res} | f = 1MHz | - | 4400 | - | | |
| Turn-on time | ton | | - | 0.35 | 1.2 | µs | |
| | tr | V _{CC} = 600V I _c = 200A | - | 0.25 | 0.6 | | |
| | tr (i) | V _{GE} = ±15V R _θ = 4.7Ω | - | 0.1 | - | | |
| Turn-off time | toff | | - | 0.45 | 1.0 | µs | |
| | tf | | - | 0.08 | 0.3 | | |
| | | | | | | | |
| Forward on voltage | V _f | I _f = 200A | T _j =25°C | - | 2.3 | 3.0 | V |
| | | | T _j =125°C | - | 2.0 | - | |
| Reverse recovery time | trr | I _f = 200A | - | - | 0.35 | µs | |

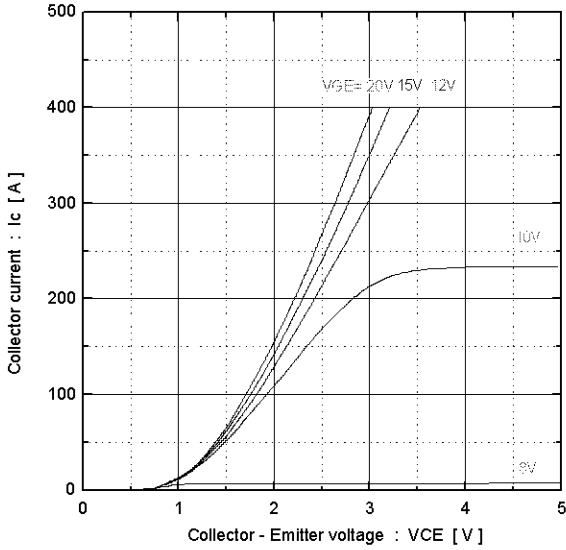
● Thermal resistance characteristics

| Items | Symbols | Conditions | Characteristics | | | Units |
|------------------------------|----------------------|----------------------------|-----------------|-------|-------|-------|
| | | | min. | typ. | max. | |
| Thermal resistance (1device) | R _{th(j-c)} | IGBT | - | - | 0.085 | °C/W |
| | | FWD | - | - | 0.18 | |
| Contact thermal resistance | R _{th(c-f)} | with Thermal Compound (*3) | - | 0.025 | - | |

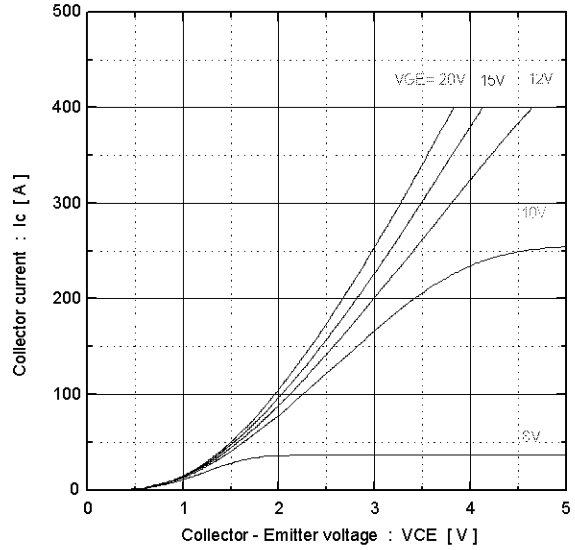
Note *3: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

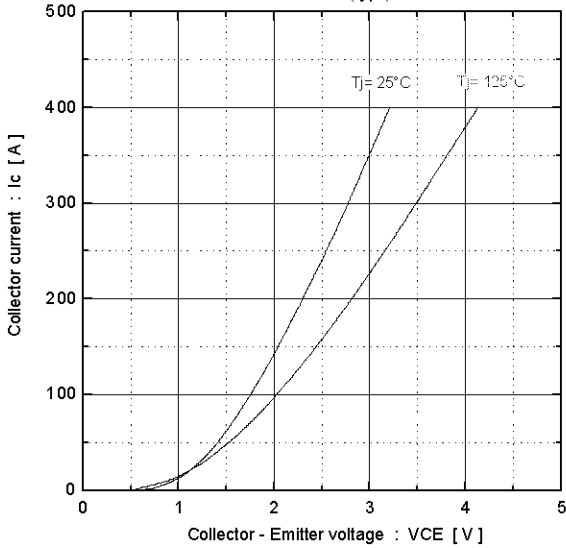
Collector current vs. Collector-Emitter voltage
T_J=25°C (typ.)



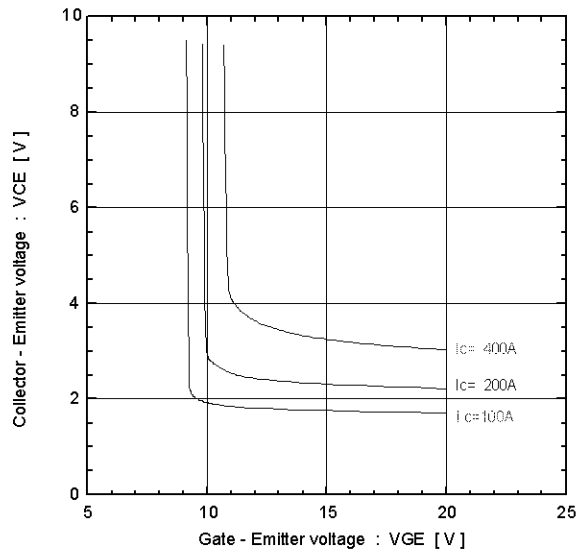
Collector current vs. Collector-Emitter voltage
T_J=125°C (typ.)



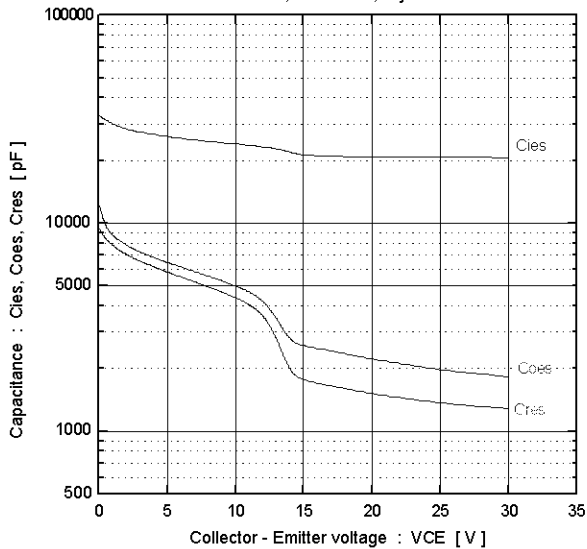
Collector current vs. Collector-Emitter voltage
VGE=15V (typ.)



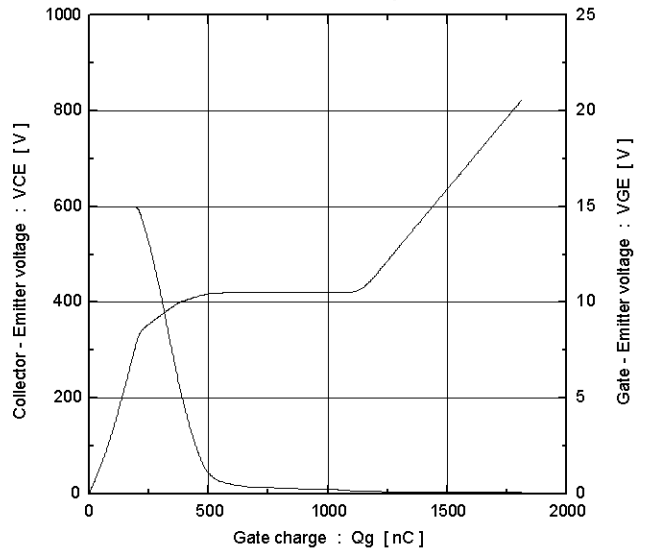
Collector-Emitter voltage vs. Gate-Emitter voltage
T_J=25°C (typ.)

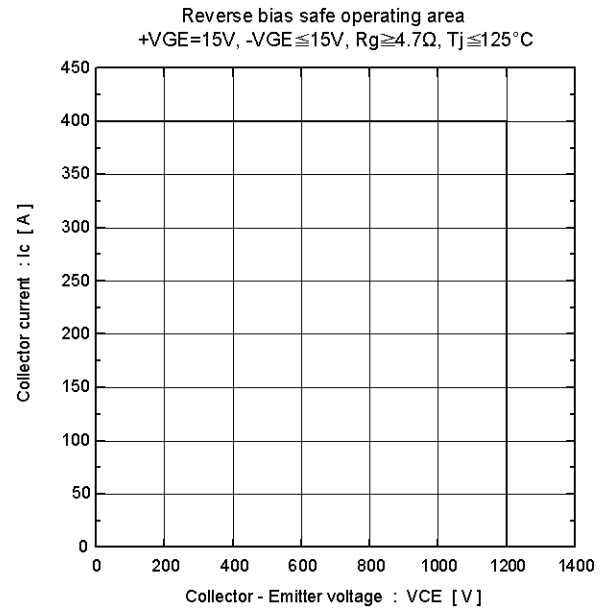
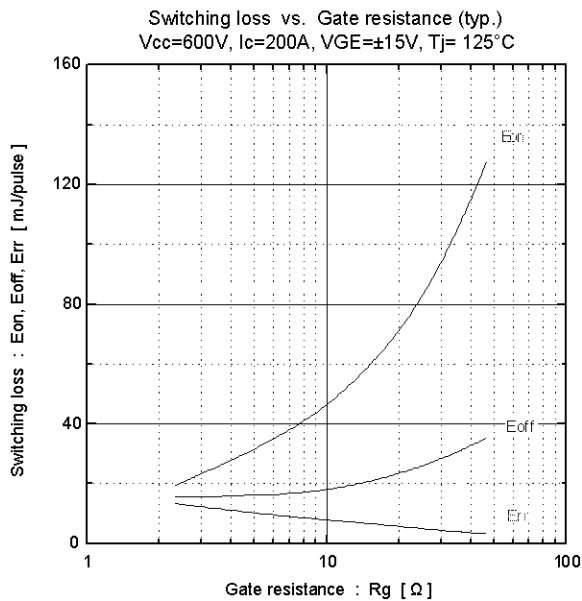
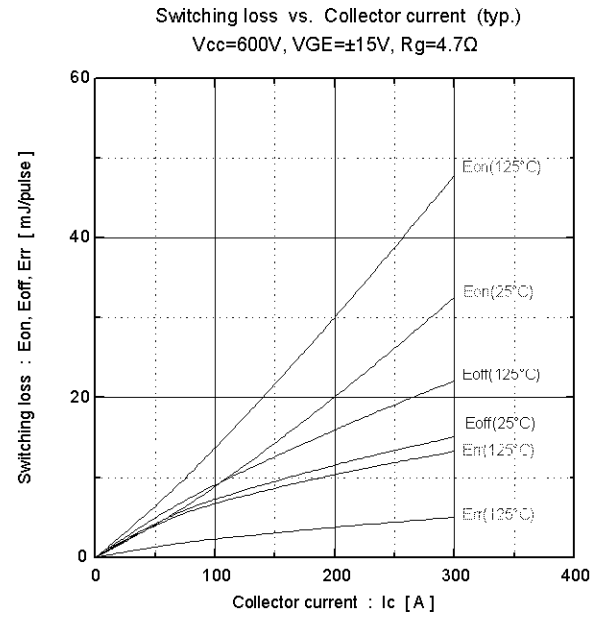
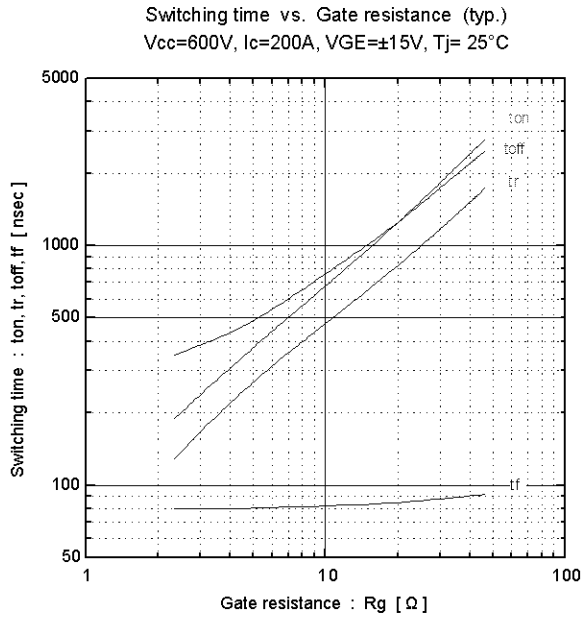
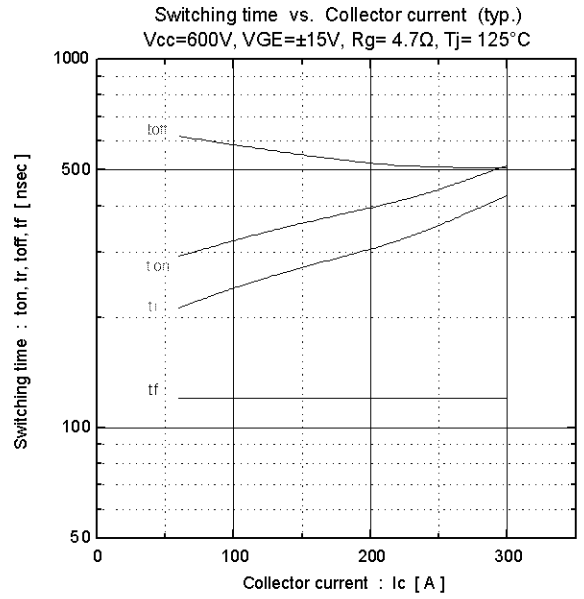
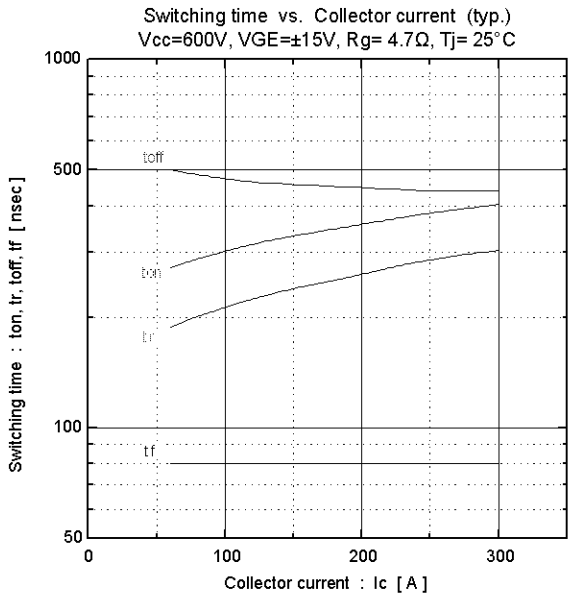


Capacitance vs. Collector-Emitter voltage (typ.)
VGE=0V, f=1MHz, T_J=25°C

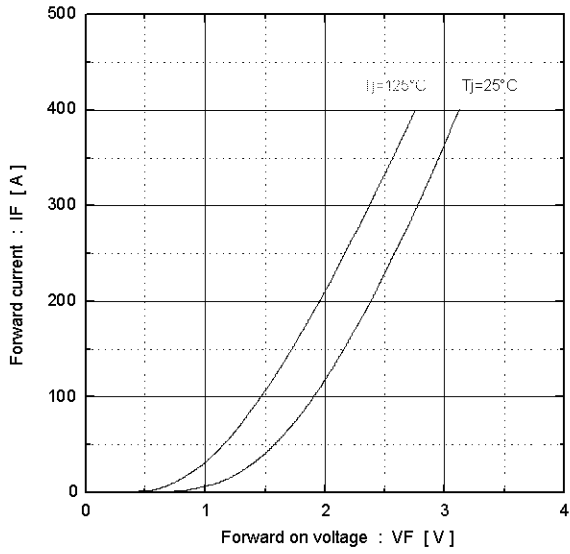


Dynamic Gate charge (typ.)
Vcc=600V, Ic=200A, T_J=25°C

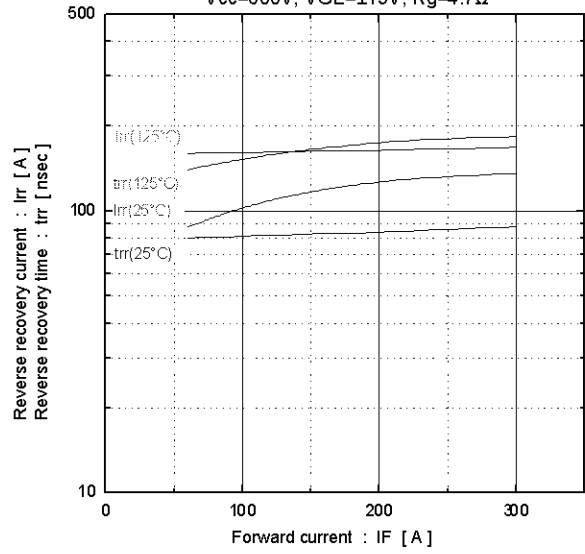




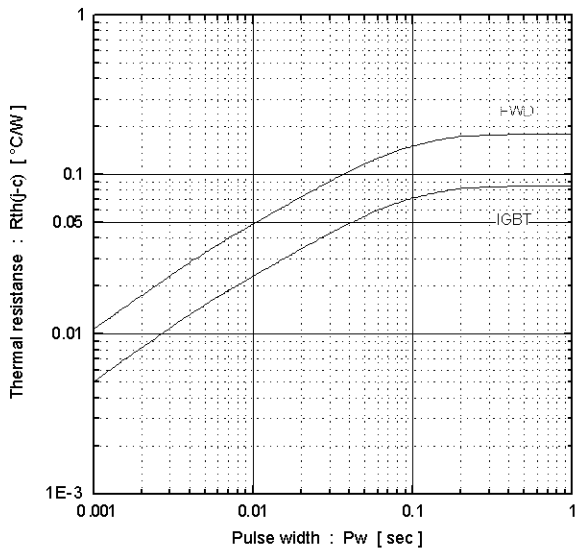
Forward current vs. Forward on voltage (typ.)



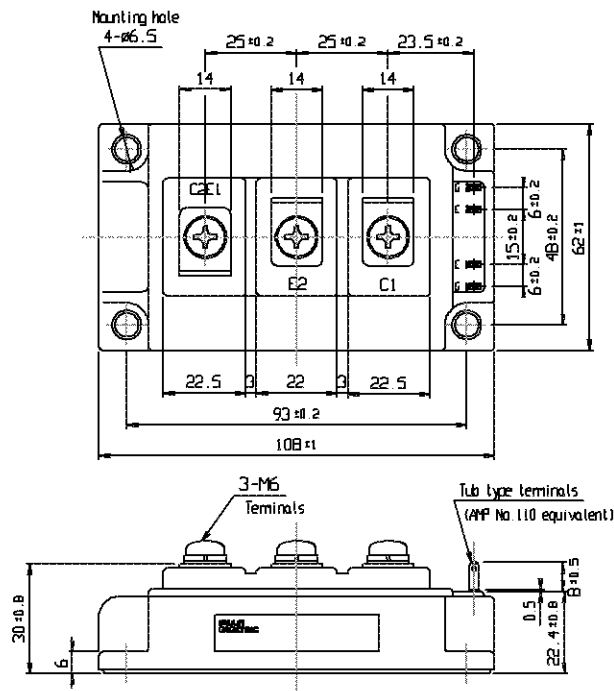
Reverse recovery characteristics (typ.)



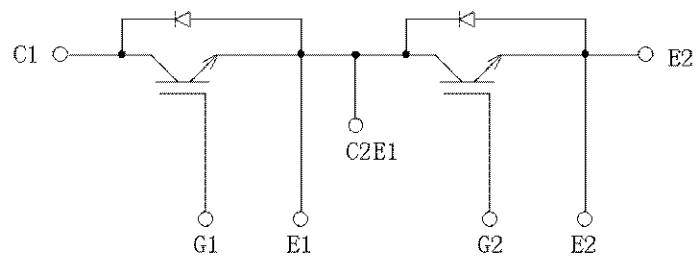
Transient thermal resistance



■ Outline Drawings, mm



■ Equivalent Circuit Schematic



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